

# Thickness dependence of critical current density in thick MgB<sub>2</sub> films

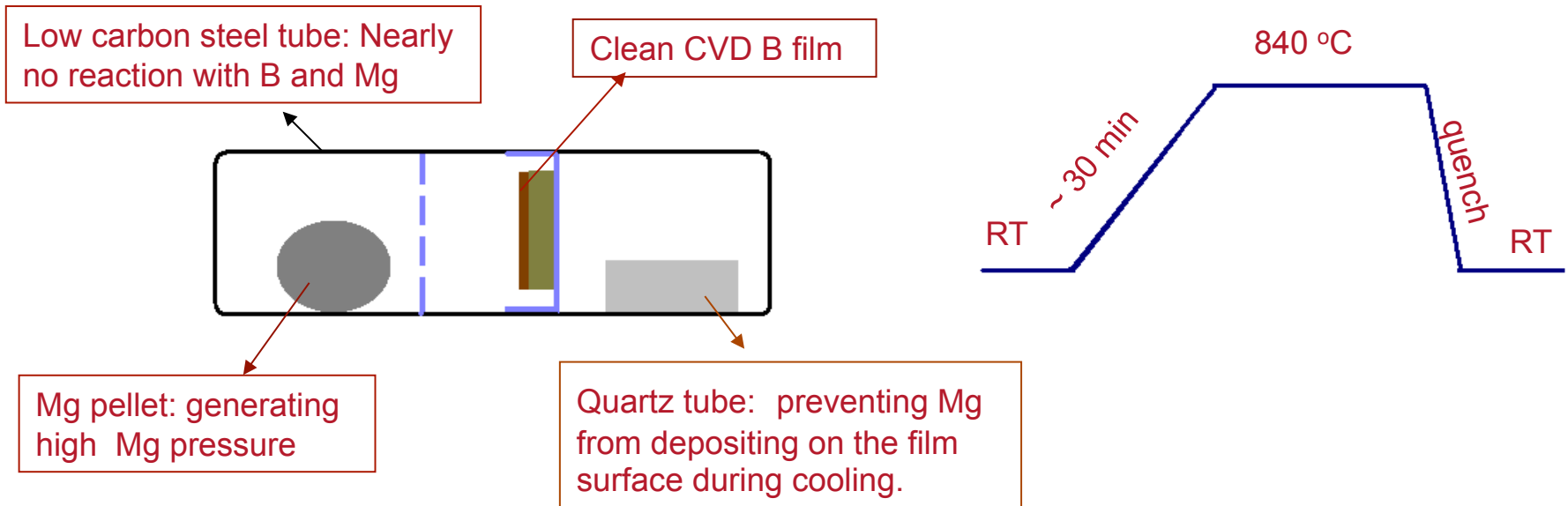
**Mina Hanna <sup>1</sup>, Shufang Wang <sup>2</sup>, Joan M. Redwing <sup>2</sup>, X. X. Xi <sup>2</sup>  
and Kamel Salama <sup>1</sup>**

<sup>1</sup> DEPARTMENT OF MECHANICAL ENGINEERING, UNIVERSITY OF HOUSTON

<sup>2</sup> MATERIALS RESEARCH INSTITUTE, THE PENNSYLVANIA STATE UNIVERSITY



# *Ex Situ* High Temperature Annealing CVD-Grown B Films in Mg Vapor

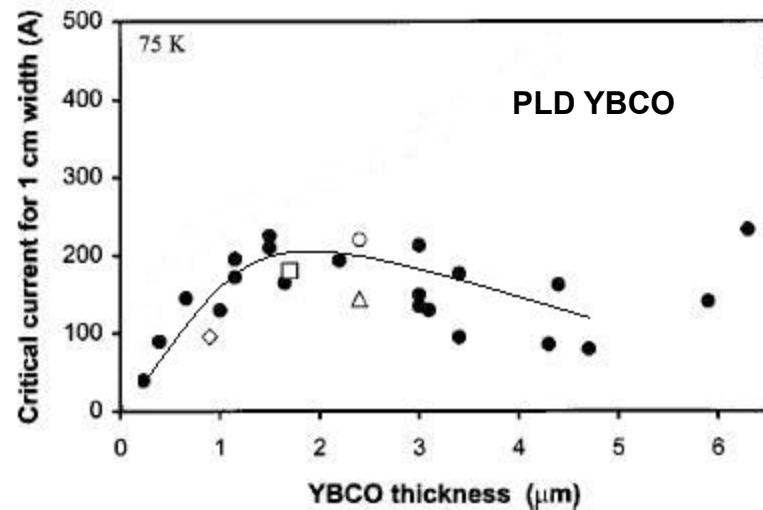
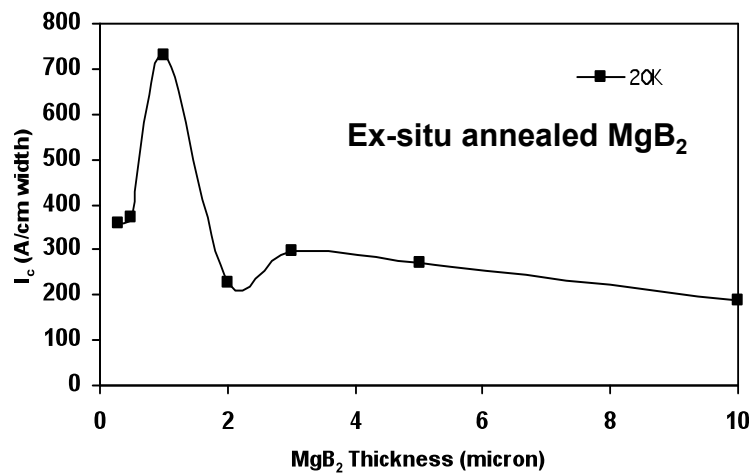
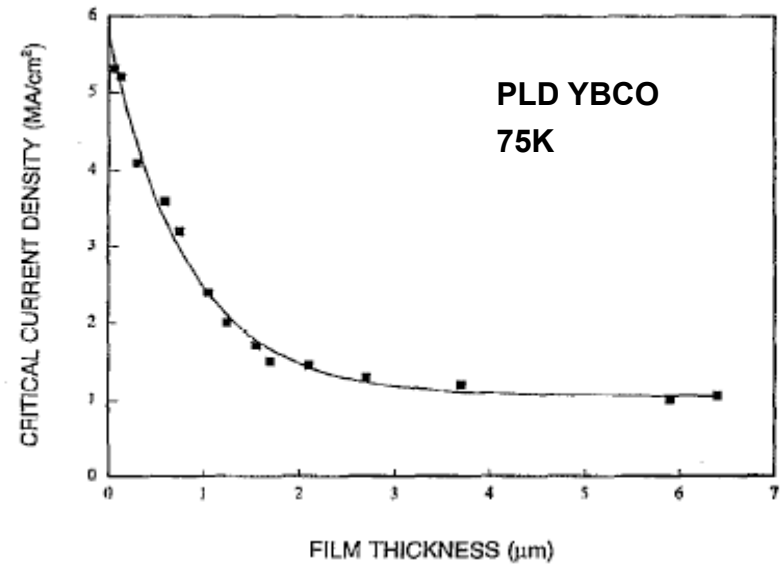
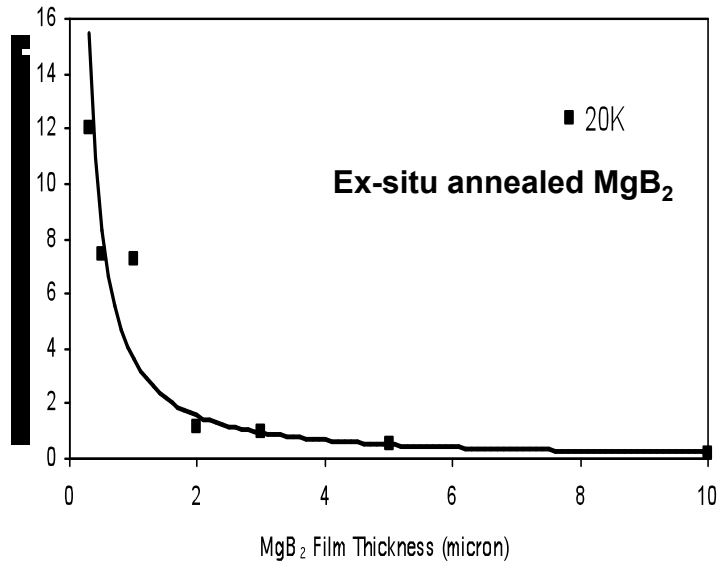


## Results of MgB<sub>2</sub> Films Fabricated for Thickness Dependence Study (*Ex Situ* Annealed at 840°C)

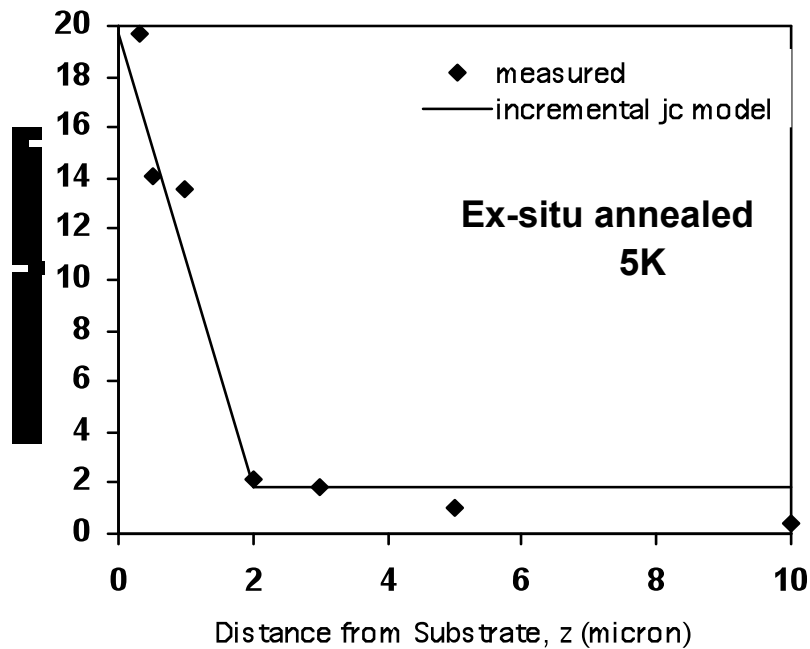
MgB <sub>2</sub> film thickness (μm)	$J_c$ (A/cm <sup>2</sup> ) @ 0T,5K	$J_c$ (A/cm <sup>2</sup> ) @ 0T,20K	$I_c$ (A/cm-w) @ 0T,5K	$I_c$ (A/cm-w) @ 0T,20K
0.3	$1.97 \times 10^7$	$1.2 \times 10^7$	591	360
0.5	$1.41 \times 10^7$	$7.42 \times 10^6$	705	371
1	$1.36 \times 10^7$	$7.28 \times 10^6$	1360	728
2	$2.1 \times 10^6$	$1.14 \times 10^6$	420	228
3	$1.79 \times 10^6$	$9.94 \times 10^5$	537	298
5	$1.03 \times 10^6$	$5.41 \times 10^5$	515	270
10	$3 \times 10^5$	$1.9 \times 10^5$	387	190

Hanna *et al*, Accepted for publishing in SC Sci. Tech.

# $J_c$ and $I_c$ Thickness Dependence (MgB<sub>2</sub> versus YBCO)

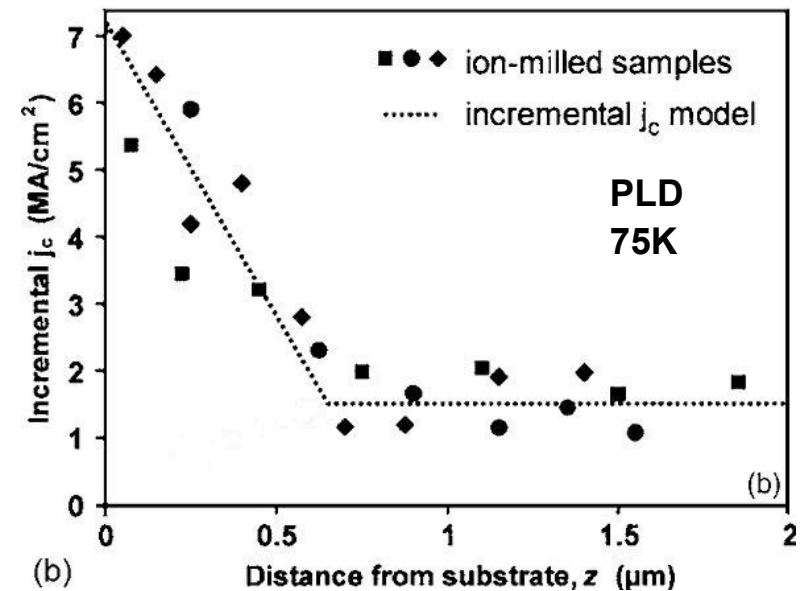


# Incremental $J_c$ Model (MgB2 vs. YBCO)



MgB2

Hanna *et al*, Accepted for publishing in SC Sci. Tech.



YBCO

Foltyn *et al*, 2005 Appl. Phys. Lett. 87 162505

# Possible Explanations for $J_c$ and $I_c$ Drop with Increasing Thickness

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- High density of flux pinning defects and dislocations near the film-substrate interface
- Vortices: as thickness  $t$  is increased, the Lorentz force, which is proportional to  $t$ , can only stay in balance with pinning forces by reducing  $J_c$
- Microstructural degradation (cracks, porosity)
- Impurity diffusion during annealing

Thank You

